

Manufactured using a new die package, the new A750Pi and A650Si/Sc Series embedded solid state drives (SSDs) are breaking endurance records. Compared with other 3D TLC drives, they deliver 66% higher endurance in native triple level cell (TLC) mode and 50% higher in pseudo single level cell (pSLC) mode, making them on par with drives built on multi-level cell (MLC) and SLC flash, respectively.

#### **Key Features**

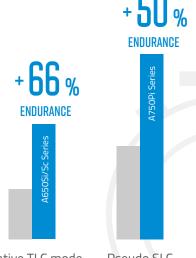
- Available in M.2 2280/2242, 2.5" & mSATA form factors
- Endurance on par with MLC & SLC flash
- 120 to 1920 GB capacities for native TLC (A650Si/A650Sc)
- 80 to 640 GB capacities for pSLC (A750Pi)
- Industrial temperature operable (A750Pi/A650Si)
- MCU-based Power Loss Protection design with Level 4 data-in-flight) protection
- LDPC ECC & RAID support
- End-to-end data path protection
- SED features\*

\*Optional

## Why A750Pi and A650Si/Sc Series ATP SSDs?

#### Endurance Suited for Write-Intensive Workloads

ATP's new 3D TLC SSDs leap to new endurance heights, thanks to a new die package. In native TLC mode, the A650Si/Sc Series delivers 66% higher TBW than other SSDs to achieve near-MLC endurance. For the A750Pi Series in pSLC mode, it's 50% higher to match SLC endurance.







# Four-Corner, Temperature Cycling, and Power Cycling Tests

Demonstrate reliable performance and stored data handling without data miscompare even under harsh conditions.



#### **End-of-Life Validation Test**

Makes sure that ATP SSDs perform reliably and maintain data integrity over their life span (and even beyond) as required.



#### PCBA Solderability Validation

Ensures effective bonding of components on the printed circuit board assembly (PCBA) for reliable electro-mechanical connections.



#### Reliability Demonstration Test (RDT)

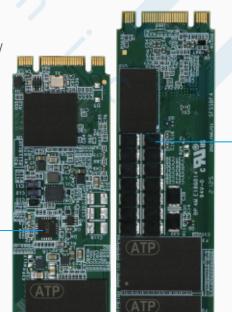
Validates the mean time between failures (MTBF) rating of the drive through actual drive-level testing instead of relying on reliability prediction systems.

## MCU-Based Power Loss Protection Design

The newly designed power loss protection (PLP) array includes a power management IC (PMIC) and firmware-programmable MCU (microcontroller unit), allowing the PLP array to perform intelligently in various temperatures, power glitches and charge states.



MCU



PLP array

### **Product Specifications**

		2.5"			M.2 2280		
Product Line	A750Pi	A650Si	A650Sc	A750Pi	A650Si	A650Sc	
Flash Type			3D .	TLC			
Flash Mode	Pseudo SLC	TLC	TLC	Pseudo SLC	TLC	TLC	
Operating Temperature (Tcase) <sup>1</sup>	-40°C	to 85°C	0°C to 70°C	-40°C	to 85°C	0°C to 70°C	
Power Loss Protection Options	Hardware + Firmware Based						
Optional SED Features	-	AES 256-bit Encry	ption, TCG Opal 2.0	-	AES 256-bit Encry	ption, TCG Opal 2.0	
Capacity	80 GB to 640 GB	120 GB to 1920 GB	120 GB to 1920 GB	80 GB to 320 GB	120 GB to 960 GB	120 GB to 960 GE	
	Performance						
Performance Sequential Read (MB/s) up to	560	560	560	560	560	560	
Performance Sequential Write (MB/s) up to	520	500	500	520	440	440	
erformance Random Read IOPS (4K,QD32) up to	95,000	100,000	100,000	94,000	100,000	100,000	
erformance Random Writes IOPS (4K, QD32) up to	86,000	91,000	91,000	86,000	88,000	88,000	
	Endurance and Reliability						
Endurance (TBW)² up to	38,400 TB	9,310 TB	9,310 TB	19,200 TB	4,655 TB	4,655 TB	
ReliabilityMTBF @ 25°C	>2,000,000 hours						
Data Retention @ 30°C³	5 years (with 10% P/E cycle)						
	Others						
Power Consumption	5V Input Power	5V Input Power	5V Input Power	3.3V Input Power	3.3V Input Power	3.3V Input Power	
imensions: L x W x H (mm)	100 x 69.9 x 7/9.2	100 x 69.9 x 7/9.2	100 x 69.9 x 7/9.2	80 x 22 x 3.35	80 x 22 x 3.35	80 x 22 x 3.35	
Certifications	CE, FCC, BSMI, UKCA, RoHS, REACH						
Warranty	5 years	2 years	2 years	5 years	2 years	2 years	
		M.2 2242			mSATA		
Product Line	A750Pi	A650Si	A650Sc	A750Pi	A650Si	A650Sc	
Flash Type			3D -	TLC			
Flash Mode							
ו ומסוו ויווטעל	Pseudo SLC	TLC	TLC	Pseudo SLC	TLC	TLC	
	Pseudo SLC -40°C t		TLC 0°C to 70°C		TLC to 85°C	TLC 0°C to 70°C	
Operating Temperature				-40°C			
Operating Temperature (Tcase) <sup>1</sup> Power Loss Protection		to 85°C	0°C to 70°C	-40°C	to 85°C	0°C to 70°C	
Operating Temperature (Tcase)¹ Power Loss Protection Options		to 85°C	0°C to 70°C Hardware + Fir	-40°C	to 85°C	0°C to 70°C ption, TCG Opal 2.0	
Operating Temperature (Tcase) <sup>1</sup> Power Loss Protection Options Optional SED Features	-40°C1	co 85°C AES 256-bit Encry	0°C to 70°C Hardware + Fir ption, TCG Opal 2.0	-40°C mware Based - 80 GB to 160 GB	to 85°C AES 256-bit Encry	0°C to 70°C ption, TCG Opal 2.0	
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential	-40°C1	co 85°C AES 256-bit Encry	0°C to 70°C Hardware + Fir ption, TCG Opal 2.0 120 GB to 480 GB	-40°C mware Based - 80 GB to 160 GB	to 85°C AES 256-bit Encry		
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential	-40°C t - 80 GB to 160 GB	20 85°C AES 256-bit Encry 120 GB to 480 GB	0°C to 70°C Hardware + Fir ption, TCG Opal 2.0 120 GB to 480 GB Perforr	-40°C mware Based - 80 GB to 160 GB mance	to 85°C AES 256-bit Encry 120 GB to 480 GB	0°C to 70°C ption, TCG Opal 2.0 120 GB to 480 GF	
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to	-40°C t - 80 GB to 160 GB	20 85°C  AES 256-bit Encry  120 GB to 480 GB  560	0°C to 70°C  Hardware + Fir ption, TCG Opal 2.0  120 GB to 480 GB  Perform 560	-40°C rmware Based - 80 GB to 160 GB mance 560	to 85°C  AES 256-bit Encry  120 GB to 480 GB  560	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GE  560	
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to erformance Random Read IOPS (4K,QD32) up to	-40°C t - 80 GB to 160 GB 560 520	AES 256-bit Encry 120 GB to 480 GB 560 440	0°C to 70°C  Hardware + Fir  ption, TCG Opal 2.0  120 GB to 480 GB  Perfore  560  440	-40°C rmware Based - 80 GB to 160 GB mance 560 520	to 85°C  AES 256-bit Encry  120 GB to 480 GB  560  440	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GE  560  440	
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to erformance Random Read IOPS (4K,QD32) up to	-40°C t  - 80 GB to 160 GB  560 520 84,500	AES 256-bit Encry 120 GB to 480 GB 560 440 100,000	0°C to 70°C  Hardware + Fir  ption, TCG Opal 2.0  120 GB to 480 GB  Perform  560  440  100,000	-40°C mware Based  - 80 GB to 160 GB mance  560  520  94,000  85,000	to 85°C  AES 256-bit Encry 120 GB to 480 GB  560  440  100,000	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GE  560  440  100,000	
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to erformance Random Read IOPS (4K,QD32) up to	-40°C t  - 80 GB to 160 GB  560 520 84,500	AES 256-bit Encry 120 GB to 480 GB 560 440 100,000	0°C to 70°C  Hardware + Fir  ption, TCG Opal 2.0  120 GB to 480 GB  Perfore  560  440  100,000  88,000	-40°C mware Based  - 80 GB to 160 GB mance  560  520  94,000  85,000	to 85°C  AES 256-bit Encry 120 GB to 480 GB  560  440  100,000	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GE  560  440  100,000	
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Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to erformance Random Read IOPS (4K,QD32) up to rformance Random Writes IOPS (4K,QD32) up to Endurance (TBW)² up to ReliabilityMTBF @ 25°C	-40°C t  - 80 GB to 160 GB  560 520 84,500 84,500	20 85°C  AES 256-bit Encry 120 GB to 480 GB  560 440 100,000 88,000	0°C to 70°C  Hardware + Fir  ption, TCG Opal 2.0  120 GB to 480 GB  Perfore  560  440  100,000  88,000  Endurance ar  2,327 TB  >2,000,00	-40°C mware Based  - 80 GB to 160 GB mance  560 520 94,000 85,000 ad Reliability 9,600 TB 00 hours	to 85°C  AES 256-bit Encry  120 GB to 480 GB  560  440  100,000  88,000	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GB  560  440  100,000  88,000	
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Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to  Endurance (TBW)² up to ReliabilityMTBF @ 25°C Data Retention @ 30°C³	-40°C t  - 80 GB to 160 GB  560 520 84,500 84,500 9,600 TB	20 85°C  AES 256-bit Encry 120 GB to 480 GB  560 440 100,000 88,000  2,327 TB	0°C to 70°C  Hardware + Fir  ption, TCG Opal 2.0  120 GB to 480 GB  Perfore  560  440  100,000  88,000  Endurance ar  2,327 TB  >2,000,00  5 years (with 100)  Oth  3.3V Input Power	-40°C mware Based  - 80 GB to 160 GB mance  560 520 94,000 85,000 and Reliability 9,600 TB 00 hours 10% P/E cycle) ers 3.3V Input Power 50.8 x 29.85 x 3.5	to 85°C  AES 256-bit Encry 120 GB to 480 GB  560 440 100,000 88,000  2,327 TB	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GE  560  440  100,000  88,000  2,327 TB	
Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity  Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to Performance (TBW)² up to ReliabilityMTBF @ 25°C Data Retention @ 30°C³  Power Consumption Pimensions: Lx Wx H (mm)	-40°C t  - 80 GB to 160 GB  560 520 84,500 84,500 9,600 TB	20 85°C  AES 256-bit Encry 120 GB to 480 GB  560 440 100,000 88,000  2,327 TB	0°C to 70°C  Hardware + Fir  ption, TCG Opal 2.0  120 GB to 480 GB  Perfore  560  440  100,000  88,000  Endurance ar  2,327 TB  >2,000,00  5 years (with 100)  Oth  3.3V Input Power  42 x 22 x 3.5	-40°C mware Based  - 80 GB to 160 GB mance  560 520 94,000 85,000 and Reliability 9,600 TB 00 hours 10% P/E cycle) ers 3.3V Input Power 50.8 x 29.85 x 3.5	to 85°C  AES 256-bit Encry 120 GB to 480 GB  560 440 100,000 88,000  2,327 TB	0°C to 70°C  ption, TCG Opal 2.0  120 GB to 480 GE  560  440  100,000  88,000  2,327 TB	

<sup>&</sup>lt;sup>1</sup> Case Temperature, the composite temperature as indicated by SMART temperature attributes.

 $<sup>^{\</sup>rm 2}$  Under highest Sequential write value. May vary by density, configuration and applications.

<sup>&</sup>lt;sup>3</sup> Data retention value may vary across different temperature ranges. It is based on experimental results and should be used only for reference.

#### **Order Information**

Ordering Information							
Product Line	Form Factor	Capacity <sup>1</sup>	Endurance <sup>2</sup>	P/N Operable with Industrial Temp.	P/N Operable with Commercial Temp.		
	2.5"	120 GB	582 TB	AF120GSTCJ-7BCIP	AF120GSTCJ-7BCXP		
		240 GB	1,164 TB	AF240GSTCJ-7BCIP	AF240GSTCJ-7BCXP		
		480 GB	2,327 TB	AF480GSTCJ-7BCIP	AF480GSTCJ-7BCXP		
		960 GB	4,655 TB	AF960GSTCJ-7BCIP	AF960GSTCJ-7BCXP		
		1920 GB	9,310 TB	AF1T92STCJ-7BCIP	AF1T92STCJ-7BCXP		
A650Si/A650Sc (Native TLC)	M.2 2242	120 GB	582 TB	AF120GSTIA-7BCIP	AF120GSTIA-7BCXP		
		240 GB	1,164 TB	AF240GSTIA-7BCIP	AF240GSTIA-7BCXP		
		480 GB	2,327 TB	AF480GSTIA-7BCIP	AF480GSTIA-7BCXP		
	M.2 2280	120 GB	582 TB	AF120GSTIC-7BCIP	AF120GSTIC-7BCXP		
		240 GB	1,164 TB	AF240GSTIC-7BCIP	AF240GSTIC-7BCXP		
		480 GB	2,327 TB	AF480GSTIC-7BCIP	AF480GSTIC-7BCXP		
		960 GB	4,655 TB	AF960GSTIC-7BCIP	AF960GSTIC-7BCXP		
	mSATA	120 GB	582 TB	AF120GSTHI-7BCIP	AF120GSTHI-7BCXP		
		240 GB	1,164 TB	AF240GSTHI-7BCIP	AF240GSTHI-7BCXP		
		480 GB	2,327 TB	AF480GSTHI-7BCIP	AF480GSTHI-7BCXP		
A750Pi (Pseudo SLC)	2.5"	80 GB	4,800 TB	AF80GSACJ-7BBIP			
		160 GB	9,600 TB	AF160GSACJ-7BBIP			
		320 GB	19,200 TB	AF320GSACJ-7BBIP			
		640 GB	38,400 TB	AF640GSACJ-7BBIP			
	M.2 2242	80 GB	4,800 TB	AF80GSAIA-7BBIP			
		160 GB	9,600 TB	AF160GSAIA-7BBIP			
	M.2 2280	80 GB	4,800 TB	AF80GSAIC-7BBIP			
		160 GB	9,600 TB	AF160GSAIC-7BBIP			
		320 GB	19,200 TB	AF320GSAIC-7BBIP			
	mSATA	80 GB	4,800 TB	AF80GSAHI-7BBIP			
		160 GB	9,600 TB	AF160GSAHI-7BBIP			
		Self-Encrypt	ing Drive upon requ	uest and on project basis.			

<sup>&</sup>lt;sup>1</sup> Amount of actual usable storage that can be utilized

Product spec and its related information are subject to change without advance notice. Please refer to  $\underline{www.atpinc.com}$  for latest information

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<sup>&</sup>lt;sup>2</sup> TBW in Sequential Write